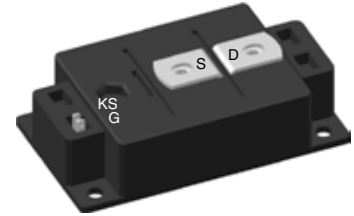
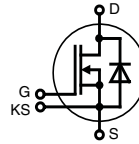


# PolarHT™ Module

N-Channel Enhancement Mode

$V_{DSS} = 200\text{ V}$   
 $I_{D80} = 1600\text{ A}$   
 $R_{DS(on)} = 1.7\text{ m}\Omega\text{ max.}$



| MOSFET    |   |                 |   |
|-----------|---|-----------------|---|
| Symbol    | Conditions  | Maximum Ratings |   |
| $V_{DSS}$ | $T_{VJ} = 25^{\circ}\text{C to } 150^{\circ}\text{C}$ | 200             | V |
| $V_{GS}$  |   | $\pm 20$        | V |
| $I_{D25}$ | $T_C = 25^{\circ}\text{C}$                            | 1900            | A |
| $I_{D80}$ | $T_C = 80^{\circ}\text{C}$                            | 1600            | A |
| $I_{F25}$ | $T_C = 25^{\circ}\text{C}$ (diode)                    | 1900            | A |
| $I_{F80}$ | $T_C = 80^{\circ}\text{C}$ (diode)                    | 1600            | A |

### Features

- PolarHT™ technology
  - low  $R_{DSon}$
  - dv/dt ruggedness
  - fast intrinsic reverse diode
- Package
  - low inductive current path
  - screw connection to high current main terminals
  - use of non interchangeable connectors for auxiliary terminals possible
  - Kelvin source terminals for easy drive
  - isolated ceramic base plate

| Symbol  | Conditions  | Characteristic Values  |   |   |   |  |  |
|---|---|--|---|---|---|--|--|
|   |   | min.   | typ.  | max.  |   |  |  |
| $(T_{VJ} = 25^{\circ}\text{C, unless otherwise specified})$                         |   |  |   |   |   |  |  |
| $R_{DSon}$  | $V_{GS} = 10\text{ V}; I_D = 1600\text{ A};$<br>$T_{VJ} = 25^{\circ}\text{C}$<br>$T_{VJ} = 125^{\circ}\text{C}$ |  | 1.58<br>3.25  | 1.7<br>3.6                                    | mΩ<br>mΩ                                      |  |  |
| $V_{GS(th)}$  | $V_{DS} = 20\text{ V}; I_D = 5\text{ mA}$   | 2.5  |   | 5   | V   |  |  |
| $I_{DSS}$   | $V_{DS} = V_{DSS}; V_{GS} = 0\text{ V};$<br>$T_{VJ} = 25^{\circ}\text{C}$<br>$T_{VJ} = 125^{\circ}\text{C}$     |  | 5.0   | 0.5   | mA<br>mA                                      |  |  |
| $I_{GSS}$   | $V_{GS} = \pm 20\text{ V}; V_{DS} = 0\text{ V}$   |  |   | 2   | μA  |  |  |
| $Q_g$<br>$Q_{gs}$<br>$Q_{gd}$   | $V_{GS} = 10\text{ V}; V_{DS} = 0.5 \cdot V_{DSS}; I_D = I_{D80}$   |  | 2900<br>600<br>1600   |   | nC<br>nC<br>nC                                |  |  |
| $t_{d(on)}$<br>$t_r$<br>$t_{d(off)}$<br>$t_f$<br>$E_{on}$<br>$E_{off}$<br>$E_{rec}$ |   | inductive load<br>$V_{GS} = 10\text{ V}; V_{DS} = 100\text{ V}$<br>$I_D = 1600\text{ A}; R_G = 1.8\ \Omega$<br>$T_{VJ} = 25^{\circ}\text{C}$ |   | 320<br>1220<br>620<br>700<br>24<br>152<br>3.7 |   | ns<br>ns<br>ns<br>ns<br>mJ<br>mJ<br>mJ |  |
| $t_{d(on)}$<br>$t_r$<br>$t_{d(off)}$<br>$t_f$<br>$E_{on}$<br>$E_{off}$<br>$E_{rec}$ |   |  | inductive load<br>$V_{GS} = 10\text{ V}; V_{DS} = 100\text{ V}$<br>$I_D = 1600\text{ A}; R_G = 1.8\ \Omega$<br>$T_{VJ} = 125^{\circ}\text{C}$ |   | 340<br>1220<br>740<br>580<br>28<br>147<br>4.9 |  | ns<br>ns<br>ns<br>ns<br>mJ<br>mJ<br>mJ |
| $R_{thJC}$<br>$R_{thJH}$  | with heat transfer paste  |  |   |   | 0.03<br>0.037                                 | 0.056                                  | K/W<br>K/W                             |

### Applications

- converters with high power density for
  - main & aux. AC drives of electric vehicles
  - DC drives
  - power supplies

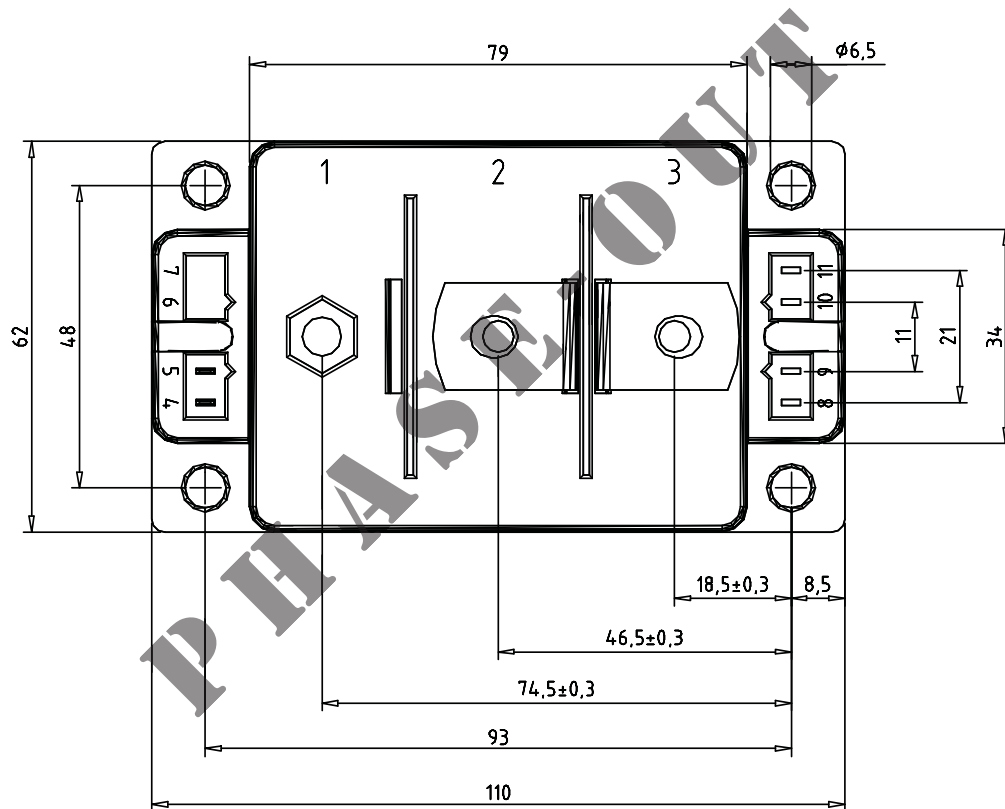
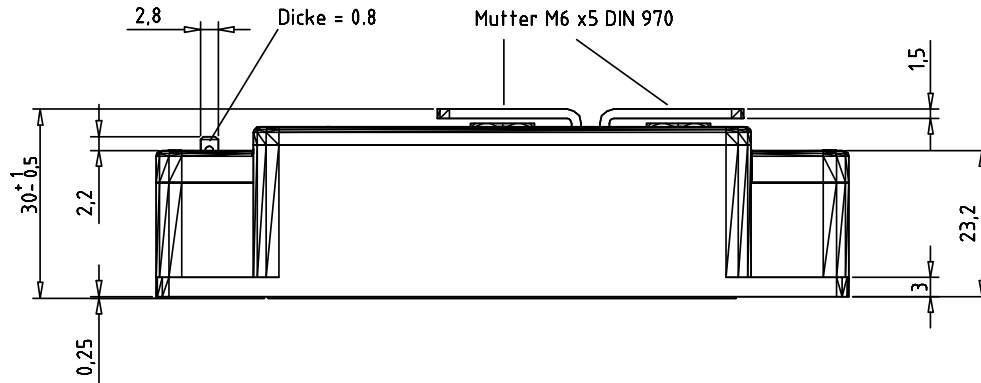
## Source Drain Diode

| Symbol                           | Conditions   | Characteristic Values |      |               |
|----------------------------------|--|-----------------------|------|---------------|
|                                  |  | min.                  | typ. | max.          |
| $V_{SD}$                         | $I_F = 1600 \text{ A}; V_{GS} = 0 \text{ V};$<br>$T_{VJ} = 25^\circ\text{C}$<br>$T_{VJ} = 125^\circ\text{C}$             |                       | 1.17 | V             |
|                                  |  |                       | 1.13 | V             |
| $t_{rr}$<br>$Q_{rr}$<br>$I_{RM}$ | $V_{DS} = 100 \text{ V}; I_F = 1600 \text{ A}$<br>$dV_F/dt = 1300 \text{ A}/\mu\text{s}$<br>$T_{VJ} = 25^\circ\text{C}$  |                       | 340  | ns            |
|                                  |  |                       | 40   | $\mu\text{C}$ |
|                                  |  |                       | 210  | A             |
| $t_{rr}$<br>$Q_{rr}$<br>$I_{RM}$ | $V_{DS} = 100 \text{ V}; I_F = 1600 \text{ A}$<br>$dV_F/dt = 1300 \text{ A}/\mu\text{s}$<br>$T_{VJ} = 125^\circ\text{C}$ |                       | 380  | ns            |
|                                  |  |                       | 56   | $\mu\text{C}$ |
|                                  |  |                       | 250  | A             |

## Module

| Symbol     | Conditions                                     | Maximum Ratings       |             |                  |
|------------|--|-----------------------|-------------|------------------|
|            |  | min.                  | typ.        | max.             |
| $T_{VJ}$   |  |                       | -40...+150  | $^\circ\text{C}$ |
| $T_{stg}$  |  |                       | -40...+125  | $^\circ\text{C}$ |
| $V_{ISOL}$ | $I_{ISOL} \leq 1 \text{ mA}; 50/60 \text{ Hz}$ |                       | 3600        | V~               |
| $M_d$      | mounting torque (M6)                           |                       | 2.25 - 2.75 | Nm               |
|            | terminal connection torque (M6)                |                       | 4.5 - 5.5   | Nm               |
| Symbol     | Conditions                                     | Characteristic Values |             |                  |
|            |  | min.                  | typ.        | max.             |
| Weight     |  |                       | 250         | g                |

| Ordering | Part Name    | Marking on Product | Delivering Mode | Base Qty | Code Key |
|----------|--------------|--------------------|-----------------|----------|----------|
| Standard | VMO 1600-02P | VMO 1600-02P       | Box             | 2        | 504288   |



**Optional accessories for modules**

**Dimensions in mm (1 mm = 0.0394")**

keyed twin plugs  
(UL758, style 1385, CSA class 5851,  
guide 460-1-1)

- Type ZY180L with wire length 350 mm  
for pins 4 (Gate, yellow wire)  
and 5 (Kelvin Source, red wire)

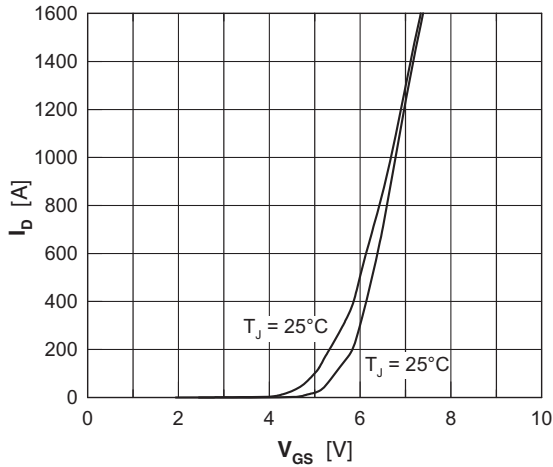


Fig. 1 Typical transfer characteristic

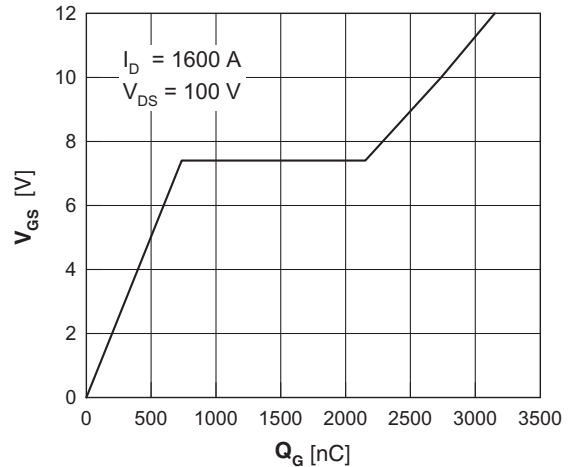


Fig. 2 Typical gate charge characteristic

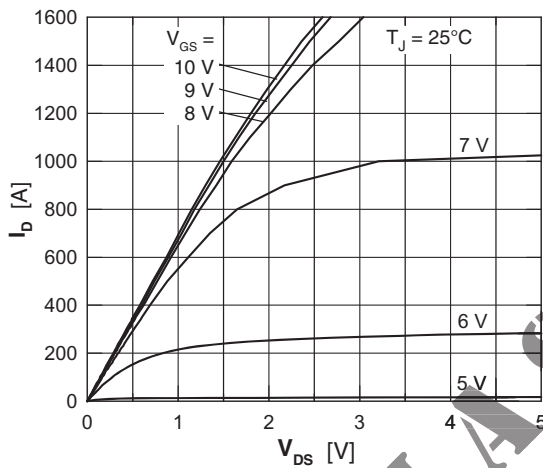


Fig. 3 Typical output characteristic

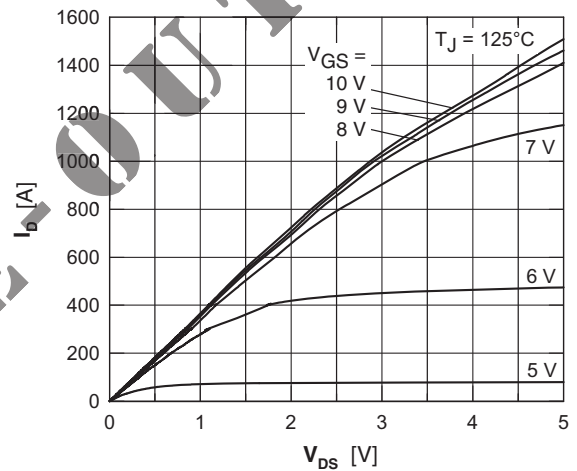


Fig. 4 Typical output characteristic

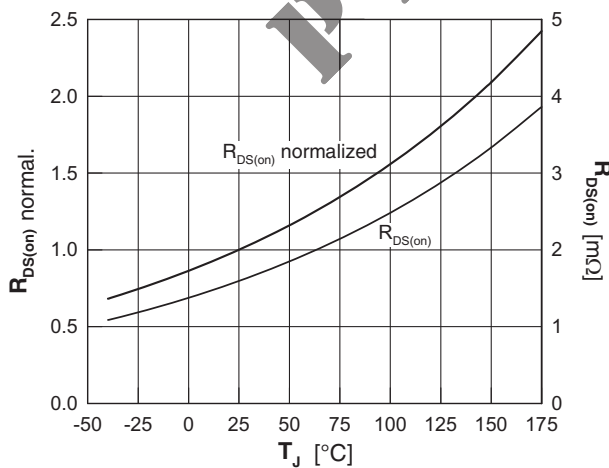


Fig. 5 Typ. drain source on-state resistance  $R_{DS(on)}$  versus junction temperature  $T_{J}$

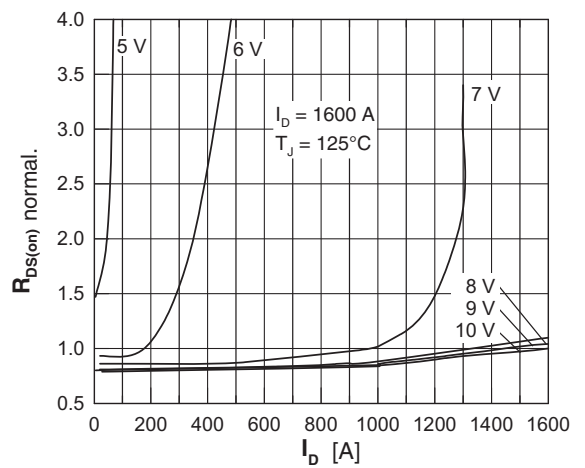


Fig. 6 Typ. drain source on-state resistance  $R_{DS(on)}$  versus  $I_D$

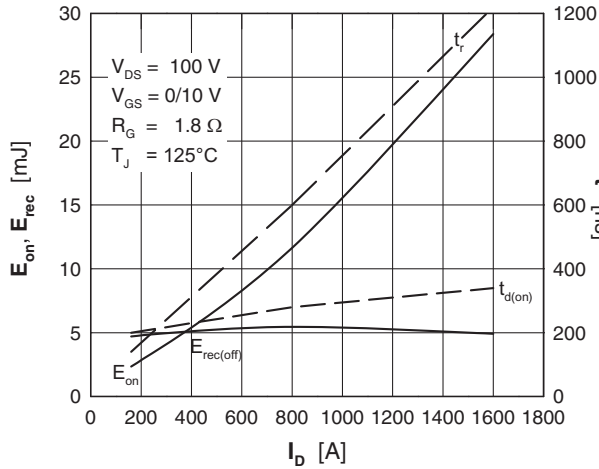


Fig. 7 Typ. turn-on energy & switching times vs. drain source current, inductive switching

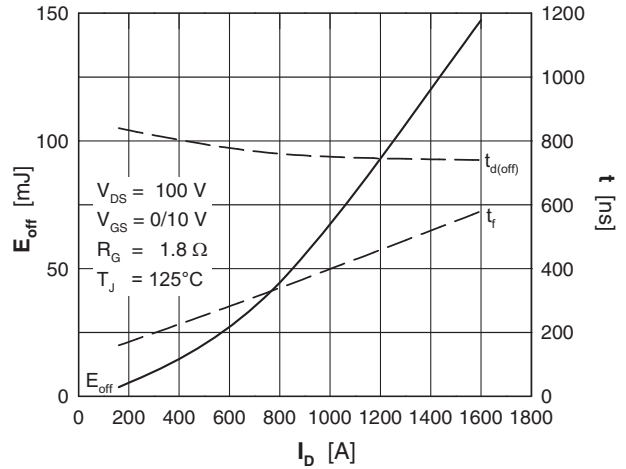


Fig. 8 Typ. turn-off energy & switching times vs. drain source current, inductive switching

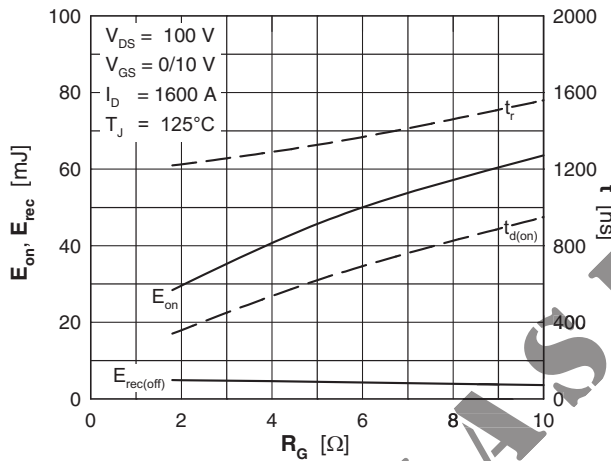


Fig. 9 Typ. turn-on energy & switching times vs. gate resistor, inductive switching

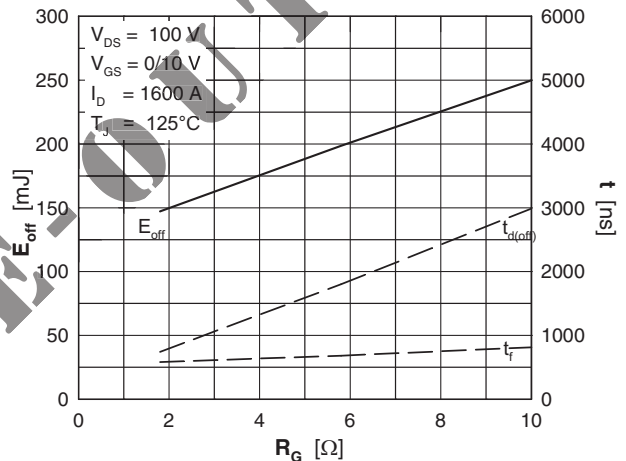


Fig. 10 Typ. turn-off energy & switching times vs. gate resistor, inductive switching

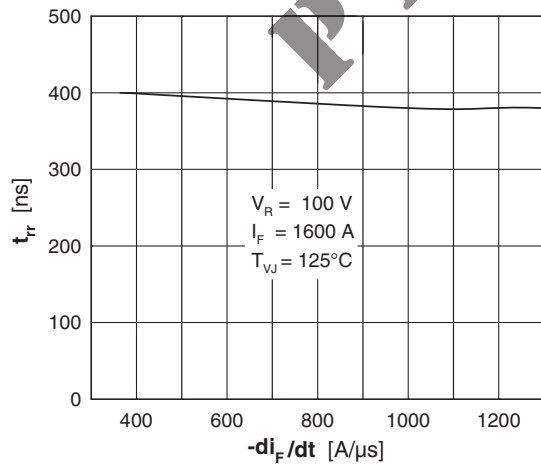


Fig. 11 Typ. reverse recovery time  $t_{rr}$  of the body diode versus  $di/dt$

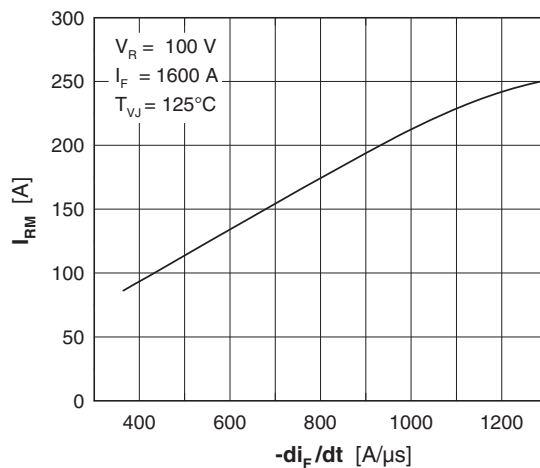


Fig. 12 Typ. reverse recovery current  $I_{RM}$  of the body diode versus  $di/dt$

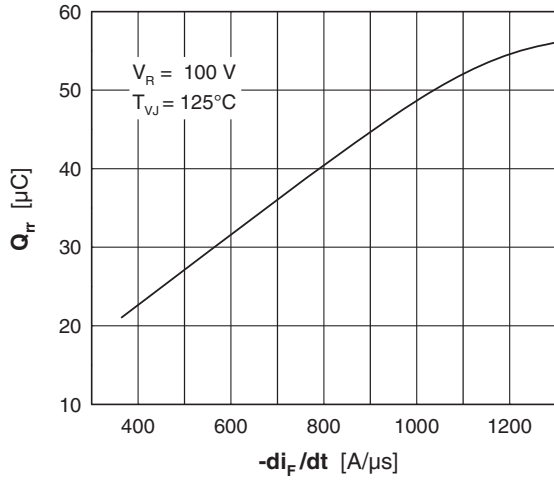


Fig. 13 Typical reverse recovery charge  $Q_{rr}$  of the body diode versus  $di/dt$

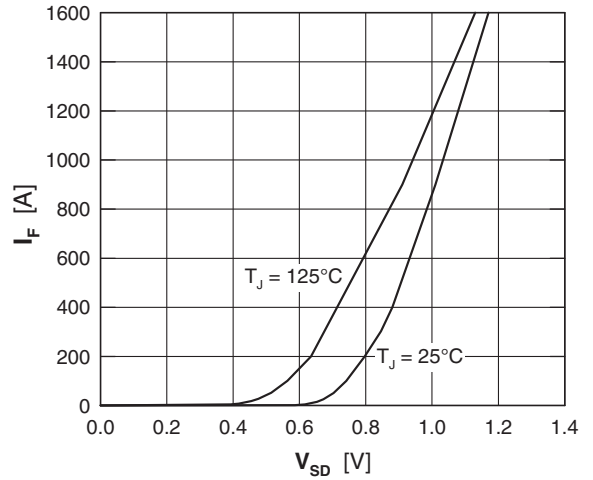


Fig. 14 Source drain current  $I_F$  (body diode) vs. typical source drain voltage  $V_{SD}$

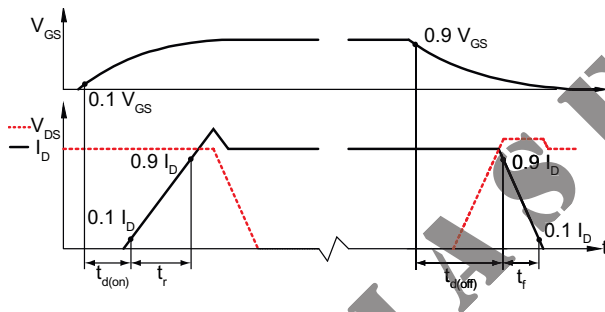


Fig. 15 Definition of switching times

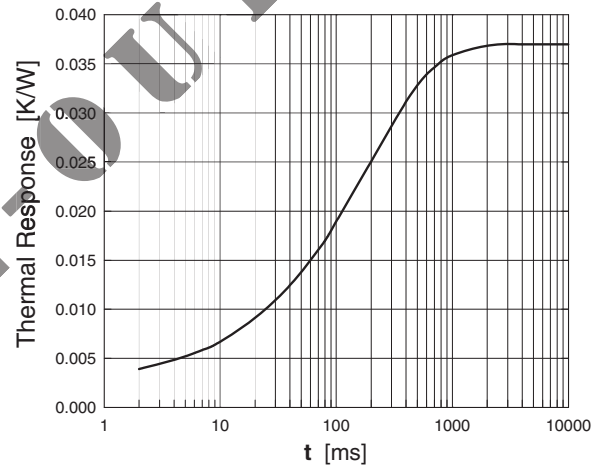


Fig. 16 Typ. thermal impedance junction to heatsink  $Z_{thjH}$  with heat transfer paste